

Description

The AO4402 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

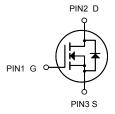
General Features

$$\begin{split} V_{DS} &= 20 V \quad I_D = 20 \text{ A} \\ R_{DS(ON)} &< 5.5 \, \text{m} \Omega \text{ @ V}_{GS} = 4.5 \text{ V} \end{split}$$



Application

Battery protection
Load switch
Uninterruptible power supply



N-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
AO4402	SOP-8	4402 XXX YYYY	3000

Absolute Maximum Ratings (T_C=25°Cunless otherwise noted)

Symbol	Parameter	Rating	Units
Vos	Drain-Source Voltage	20	V
Vgs	Gate-Source Voltage	rce Voltage ±12	
	Drain Current – Continuous (Tc=25°C)	20	А
ľσ	Drain Current – Continuous (Tc=70 °C)	16	А
I _{DM}	Drain Current – Pulsed1	140	А
EAS	Single Pulse Avalanche Energy ²	162	mJ
IAS	Single Pulse Avalanche Current ²	Single Pulse Avalanche Current ² 57	
P_D	Power Dissipation (Tc=25°C)	3.1	
Тѕтс	Storage Temperature Range	ture Range -55 to 150 °C	
TJ	Operating Junction Temperature Range	-55 to 150 °C	
$R_{ heta JA}$	Thermal Resistance Junction to ambient	40	°C/W



Electrical Characteristics Ta = 25°C

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Drain-Source Breakdown Voltage	VDSS	ID=250 uA, Vgs=0V	20			V	
Zero Gate Voltage Drain Current	Inco	VDS=20V, VGS=0V			1	uA	
Zero Gate Voltage Drain Current	IDSS	VDS=20V, VGS=0V, TJ=55℃			5	uA	
Gate-Body Leakage Current	Igss	VDS=0V, VGS= \pm 12V			±100	nA	
Gate Threshold Voltage	VGS(th)	VDS=VGS , ID=250uA	0.5		1.6	V	
	RDS(ON)	Vgs=4.5V, ID=20A			5.5	m Ω	
Static Drain-Source On-Resistance		Vgs=4.5V, ID=20A TJ=125℃			7		
		Vgs=2.5V, ID=18A			7		
On State Drain Current	Id(on)	Vgs=10V, Vps=5V	140			Α	
Forward Transconductance	grs	VDS=5V, ID=20A		105		S	
Input Capacitance	Ciss		3080		4630		
Output Capacitance	Coss	Vgs=0V, Vps=10V, f=1MHz	520		960	pF	
Reverse Transfer Capacitance	Crss		350		810		
Gate Resistance	Rg	Vgs=0V, Vps=0V, f=1MHz	0.6		2.1	Ω	
Total Gate Charge	Qg		28		43		
Gate Source Charge	Qgs	Vgs=10V, Vds=10V, Id=20A	7		11	nC	
Gate Drain Charge	Qgd		7		17		
Turn-On DelayTime	td(on)			7			
Turn-On Rise Time	tr	Vgs=10V, Vps=10V, RL=0.5Ω,		8		ns	
Turn-Off DelayTime	td(off)	Rgen=3Ω		70			
Turn-Off Fall Time	tf			18			
Body Diode Reverse Recovery Time	trr	In- 200 dulde- 5000/up	13		20		
Body Diode Reverse Recovery Charge	Qrr	IF= 20A, di/dt= 500A/us	29		43	nC	
Maximum Body-Diode Continuous Current	Is				4	Α	
Diode Forward Voltage	VsD	Is=1A,VGS=0V			1	V	
		-					

Note : The static characteristics in Figures 1 to 6 are obtained using <300 μs pulses, duty cycle 0.5% max.





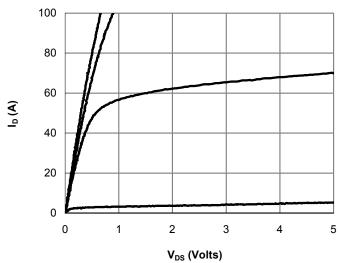
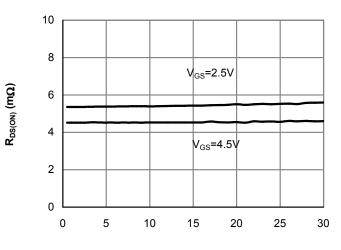


Fig 1: On-Region Characteristics (Note E)



I_D (A)
Figure 3: On-Resistance vs. Drain Current and
Gate Voltage (Note E)

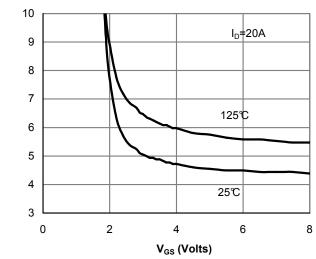


Figure 5: On-Resistance vs. Gate-Source Voltage (Note E)

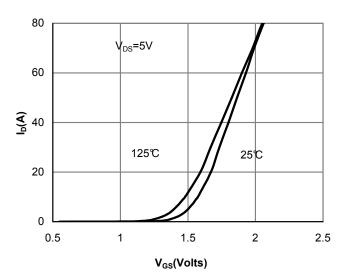
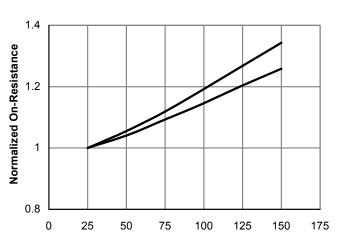
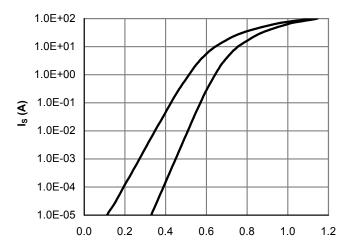


Figure 2: Transfer Characteristics (Note E)



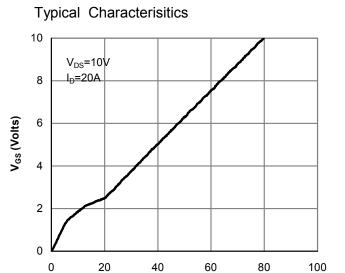
Temperature (℃)
Figure 4: On-Resistance vs. Junction Temperature
(Note E)

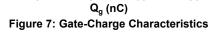


V_{SD} (Volts)
Figure 6: Body-Diode Characteristics (Note E)

R_{DS(ON)} (mΩ)







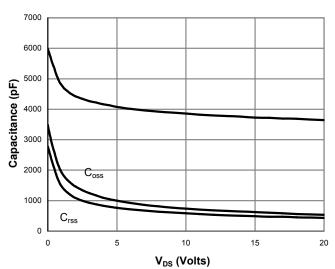


Figure 8: Capacitance Characteristics

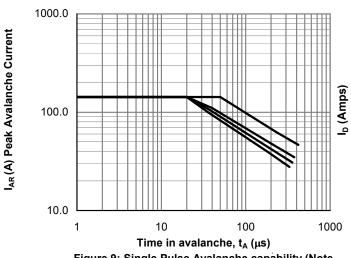
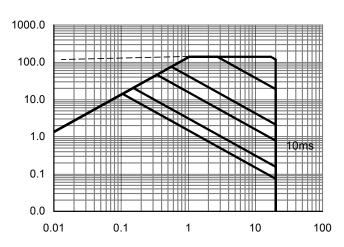


Figure 9: Single Pulse Avalanche capability (Note



V_{DS} (Volts)

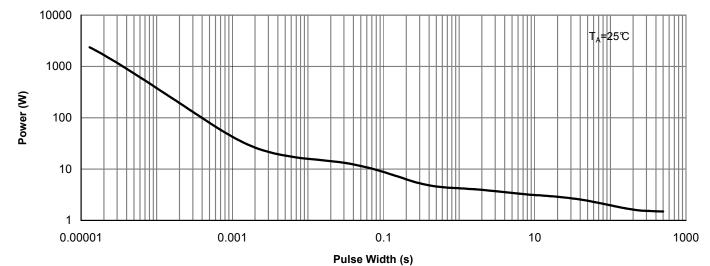


Figure 11: Single Pulse Power Rating Junction-to-Ambient (Note F)



Typical Characterisitics

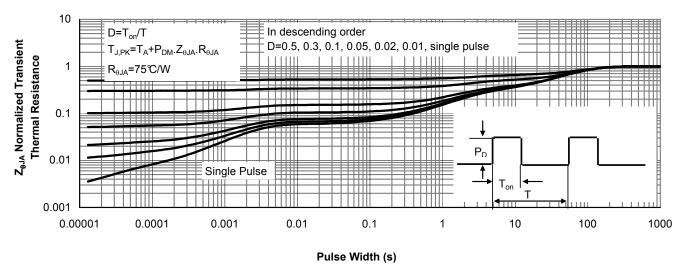
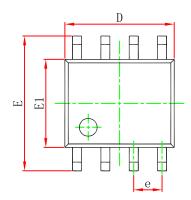
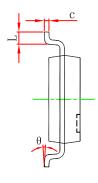


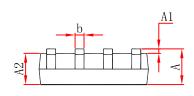
Figure 12: Normalized Maximum Transient Thermal Impedance (Note F)



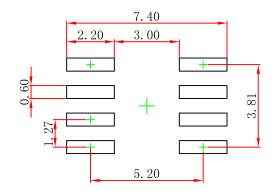
SOP-8 Package Outline Dimensions







Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
A	1.350	1.750	0.053	0.069	
A1	0.100	0. 250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0. 020	
c	0.170	0. 250	0.007	0.010	
D	4.800	5.000	0. 189	0. 197	
e	1.270 (BSC)		0.050 (BSC)		
E	5.800	6. 200	0. 228	0. 244	
E1	3.800	4.000	0. 150	0. 157	
L	0.400	1. 270	0.016	0.050	
θ	0°	8°	0°	8°	



- Note: 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.



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